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NC7WV125 TinyLogic® ULP-A Dual Buffer with 3-STATE Output

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General Description

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The NC7WV125 is a dual buffer with 3-STATE output from Fairchild's Ultra Low Power-A (ULP-A) Series of TinyLogic®. ULP-A is id eal for applications that require extreme high speed, high drive and low power. This product is designed for wide low voltage operating range (0.9V to 3.6V $V_{\rm CC}$) and applications that require more drive and speed than the TinyLogic ULP series, but still offer best in class low power operation.

The NC7WV125 is uniquely designed for optimized power and speed, and is fabricated with an advanced CMOS technology to ach ieve high-speed operation while maintaining low CMOS power dissipation.

Features

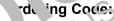
- $\blacksquare~0.9V$ to 3.6V V_{CC} supply operation
- 3.6V over-voltage tolerant I/O's at V_{CC} from 9V to 3.
- Extremely High Speed t_{PD}
- 1.0 ns typ for 2.7V to 3.6V V_{CC}
- 2.0 ns typ for 2.3V to 2.7V

3.0 ns typ for 1.65 °o 1.95\ 3.5 ns typ foi 4V t⊾ 6V V_{CC}

6.0 ns m for 1. to 1.

* ns t, 'u. ''

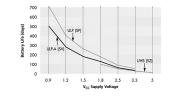
- Pc r-Oi. gh impedance is puts and outp
- High ntic ve (I_{OH}/'_{OL}/ ±24 mA 遭 3.00V V_{CC}
- 18 mA @ 2.30V V_{CC}
 - ±6 mA. (フy 1.65V V_{CC} ±4 いん @ 1.4^V v_ir(
 - ±?.mA @ 1.1. V.c
 - ±0.1 mJ @ 0.9V V_{CC}
- Uses proprietary QU et Series™ noise/EMI reduction vircuitry
 Ultra sn all MicroPak™ Pb-Free package
- Ultra low dynamic power



	Jrder Nu nber	Package Number	Product Code Top Mark	SEN	Package Description		Supplied As
	1'C7WV125K8X	МАБ08А	W1/25	8-Lead US8, JE	EDEC MO-187, Variation C	CA 3.1mm Wide	3k Units on Tape and Reel
Λ.							

Pb-Free package per JFPECJ-STL-020B.

Battery Life vs. V_{CC} Supply Voltage



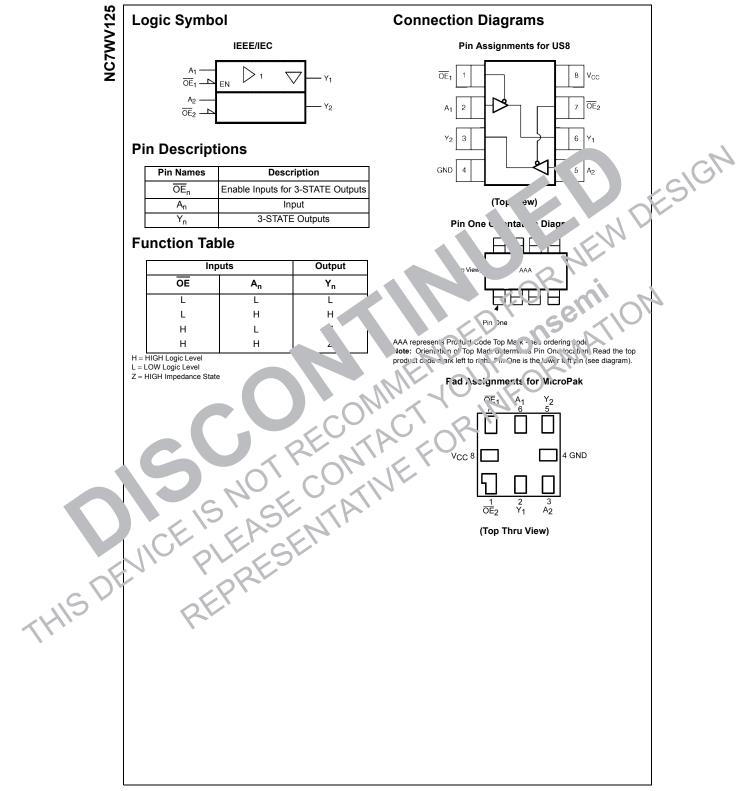
TinyLogic ULP and ULP-A with up to 50% less power consumption can extend your battery life significantly. Battery Life = (V_{battery} *b)/(P_{device})/24hrs/day

Where, $P_{device} = (I_{CC} * V_{CC}) + (C_{PD} + C_L) * V_{CC}^2 * f$

Assumes ideal 3.6V Lithium lon battery with current rating of 900mAH and derated 90% and device frequency at 10MHz, with C_L = 15 pF load

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Abs	olute Maximum Ra	•		Recomr Conditio			ting		NC7WV125
Supply	Voltage (V _{CC})	-0.5V	to +4.6V	Conditio	UIIS (Note	3)			Š
DC Inp	out Voltage (V _{IN})	-0.5V	to +4.6V	Supply Volta	age			0.9V to 3.6V	2
DC Ou	tput Voltage (V _{OUT})			Input Voltag	e (V _{IN})			0V to 3.6V	28
HIG	H or LOW State (Note 2)	–0.5V to V _C	_{CC} +0.5V	Output Volta	age (V _{OUT})				01
V _{CC}	= 0V		to +4.6V	$V_{\rm CC} = 0.0$				0V to 3.6V	
	out Diode Current (I _{IK}) V _{IN} < 0V		±50 mA		OW State			0V to V _{CC}	
	tput Diode Current (I _{OK})			Output Curr					
	_T < 0V		–50 mA	V _{CC} = 3.0	011 0	L		<u>+24.</u> 0 mA	
	T > V _{CC}		+50 mA	$V_{CC} = 2.3$				בוס. יA	FS
	tput Source/Sink Current (I _{OH} /I		± 50 mA	00	5V to 1.95V			±6.0 \	
	$_{\rm C}$ or Ground Current per	OL/	2 00 11/1	$V_{\rm CC} = 1.4$				±4.0 r	.C
	bly Pin (I _{CC} or Ground)		± 50 mA	$V_{CC} = 1.4$ $V_{CC} = 1.1$				An.	
-	e Temperature Range (T _{STG})	−65°C to		$V_{\rm CC} = 0.9$				±0.1 mA	OV.
Storag	e temperature range (T _{STG})	-05 C 10	1100 0	Free Air Op		peratu (T ₄		.J°C to ⊣ 85°C	
				-			4)	.0 0 10 + 55 0	
					V to . V, V,		\sim	10 ns/V	
				Note 1: A. saf. f the				beyond which the hould not be per-	
								Electric Chalac-	\square
								imum liatiligs. The tild conditions for	
				ctual devic	eration.	\mathbf{V}	G	> へい	Ŷ
				-	lute Maximum F				
				Nc : Unused	inputh must be	held !:: GH o. !	W. The	y may i ot float.	
DC	Electrical Charac*	tic.		NE		JK.	R		
		- tic.		= + 2±°C		C to +25° C	Units	Conditions	_
Symbo	I Parameter		Mir	Mex	Min	C to +05 0 Max	Units	Conditions	-
	I Parameter HIGH Level	.90	Min 0.65 × V _C	Max C	Min 0.65 ⊻ √ _C ;		Units	Conditions	-
Symbo	I Parameter	.90 1.10 ≤ V _{CC} ≤ 1.30	Min 0.65 x √ _C 0.65 x √ _C	Mex C	Min 0.65 ⊻ √ _{C 2} (.65 1 √ _{CC}		Units	Conditions	-
Symbo	I Parameter HIGH Level	90 1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.30	Min 0.65 × V _C 0.65 × V _C 0.65 × V _C	Max	Min 0.65 × V _C 0.65 × V _{CC} 0.35 × V _{CC}		Units V	Conditions	-
Symbo	I Parameter HIGH Level	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.00\\ 1.65 \leq V_{CC} \leq 1.95 \end{array}$	Min 0.65 × V _C 2.65 × V _C 0.65 × V _C 0.35 × V _C	Max	Min 0.65 × √ _C 2 0.65 × √ _{CC} 0.65 × V _{CC}			Conditions	-
Symbo	I Parameter HIGH Level	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\end{array}$	Min 0.65 × V _C 2.65 × V _C 0.65 × V _C 0.35 × V _C	Max	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$			Conditions	-
Symbo	I Parameter HIGH Level Input Voltage	90 $1.10 \le V_{PC} \le 1.30$ $1.40 \le V_{CC} \le 1.95$ $2.30 \le V_{CC} \le 2.10$ $2.70 \le V_{CC} \le 3.10$	Min 0.65 × V _C 2.65 × V _C 0.65 × V _C 0.35 × V _C	Mex	Min 0.65 × √ _C 2 0.65 × √ _{CC} 0.65 × √ _{CC}	Max		Conditions	_
Symbo	I Parameter HIGH Level Input Voltage	$.90$ $1.10 \le V_{CC} \le 1.30$ $1.40 \le V_{CC} \le 1.95$ $2.30 \le V_{CC} \le 1.95$ $2.30 \le V_{CC} < 2.10$ $2.70 \le V_{CC} \le 3.10$ 0.90	Min 0.65 × V _C 2.65 × V _C 0.65 × V _C 0.35 × V _C	Mex 0 0 0.35 x V _{CC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Max 0.35 x V _{CC}		Conditions	_
Symbo	I Parameter HIGH Level Input Voltage	$\begin{array}{c}90\\ \hline 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ i.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ \hline 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ \end{array}$	Min 0.65 × V _C 2.65 × V _C 0.65 × V _C 0.35 × V _C	<u>Мех</u> с 0.35 x V _{CC} 0.35 x V _{CC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Max 0.35 x V _{CC} 0.35 x V _{CC}	v	Conditions	-
Symbo	I Parameter HIGH Level Input Voltage	$\begin{array}{c}90\\ \hline90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ \circ 65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ \hline 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ \hline1 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{-C} \leq 1.50\\ \end{array}$	Mii 0.65 × V _☉ 0.65 × V _☉ 0.65 × V _☉ 1.6 2.5	Mex 0 0 0.35 x V _{CC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Max 0.35 x V _{CC}		Conditions	-
Symbo	I Parameter HIGH Level Input Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{UC} \leq 1.51\\ 1.65 \leq V_{CC} \leq 1.95 \end{array}$	Mii 0.65 × V _☉ 0.65 × V _☉ 0.65 × V _☉ 1.6 2.5	Мех 0.35 х V _{CC} 0.35 х V _{CC} 0.35 х V _{CC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC}	v	Conditions	_
Symbo	I Parameter HIGH Level Input Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} < 2.70\\ \end{array}$	Mii 0.65 × V _☉ 0.65 × V _☉ 0.65 × V _☉ 1.6 2.5	Мах 0.35 х V _{CC} 0.35 х V _{CC} 0.35 х V _{CC} 0.35 х V _{CC} 0.35 х V _{CC}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Max 0.35 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC}	v	Conditions	_
Symbo V _{IH}	I Parameter HIGH Level Input Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{UC} \leq 1.51\\ 1.65 \leq V_{CC} \leq 1.95 \end{array}$	Min 0,5≕ V _C 9,65 × V ₂ 0,65 × V ₂ 0,65 × V ₂ 1.6 2,5	Мах С 0.35 x V _{CC} 0.35 x V _{CC}	Win 0.65 × Vc2 C.65 × Vc2 0.65 × Vc2 0.65 × Vc2 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	Conditions	-
Symbo V _{IH}	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} < 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ \hline 0.90\\ \hline \end{array}$	Min 0.5 = √C_0 0.65 × V_0 0.65 × V_0 0.75 ∧ C_0 1.6 2.5 V _{CC} − 0.1	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 C.65 × Vc2 0.65 × Vc2 0.65 × Vc2 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	Conditions	-
Symbo V _{IH}	I Parameter HIGH Level Input Voltage OW Level ut Voltage HIGH Level Output Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.65 \leq V_{UC} \leq 1.95\\ 2.50 \leq V_{CC} < 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ \end{array}$	Min 0.5 = √C 9.65 × V_0 0.65 × V_0 0.65 × V_0 0.75 ∧ C 1.6 2.7 V _{CC} − 0.1 V _{CC} − 0.1	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 C.65 × Vc2 0.65 × Vc2 0.65 × Vc2 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v		-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level ut Voltage HIGH Level Output Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} < 2.30\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ \end{array}$	Min 0.5 = √C_C 0.65 × V_C 0.65 × V_C 0.75 ∧ /C_C 1.6 2.5 V _{CC} − 0.1 V _{CC} − 0.2 V _{CC} − 0.2	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 C.65 × Vc2 0.65 × Vc2 0.65 × Vc2 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	Conditions	-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level ut Voltage HIGH Level Output Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.40\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.55 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.60\\ \hline \end{array}$	Min 0.5 = √C_C 0.65 × V_C 0.65 × V_C 0.75 ∧ C_C 1.6 2.5 V _{CC} − 0.1 V _{CC} − 0.2 V _{CC} − 0.2 V _{CC} − 0.2	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × V_C C.65 × V_CC 0.65 × V_CC 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v		-
Symbo	I Parameter HIGH Level Input Voltage OW Level Jut Voltage HIGH Level Output Voltage	$\begin{array}{c}30\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} < 2.10\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.65 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ \hline 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.50\\ \end{array}$	Min 0.5 = √C_C 2.65 × V_C 0.65 × V_C 0.75 × V_C	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 0.65 × Vc2 0.65 × Vc2 0.65 × Vc2 1.6 2.0	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	I _{OH} = -100 μA	-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level , ut Voltage HIGH Level Output Voltage	$\begin{array}{c}30\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 2.10\\ 0.90\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ \end{array}$	Min 0.5 = √C 2.65 × V_C 0.65 × V_C 0.75 × V_C	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × V_{C2} 0.65 × V_{C2} 0.65 × V_{C2} 0.65 × V_{C2} 1.6 2.0 V _{CC} - 0.1 V _{CC} - 0.1 V _{CC} - 0.2	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	I _{OH} = -100 μA I _{OH} = -2.0 mA	-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level Jut Voltage HIGH Level Output Voltage	$\begin{array}{c}30\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 2.50 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.3$	Mi. 0.5 - √C 0.65 × V_C 0.65 × V_C 0.75 × V_C 0.75 × V_C 0.75 × V_C 0.75 × V_C VCC - 0.1 VCC - 0.2	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × V_C 0.65 × V_CC 0.65 × V_CC 1.6 2.0 V _{CC} - 0.1 V _{CC} - 0.1 V _{CC} - 0.2 V _{CC} - 0.2 V _{CC} - 0.2	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	I _{OH} = -100 μA	-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}30\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 1.95\\ 3.90\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 1.40 \leq V_{CC} \leq 1.50\\ 2.70 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 1.65 \leq V_{CC} \leq 3.60\\ 1.10 \leq V_{CC} \leq 3.60\\ 1.10 \leq V_{CC} \leq 1.30\\ \end{array}$	Mi. 0.5 VC 9.65 VC 0.65 VC 0.75 VC 1.6 2.5 VCC 0.75 VCC 0.75 VCC 0.75	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × V_{C2} 0.65 × V_{C2} 0.65 × V_{C2} 0.65 × V_{C2} 1.6 2.0 V _{CC} - 0.1 V _{CC} - 0.1 V _{CC} - 0.2	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	$I_{OH} = -100 \ \mu A$ $\overline{I_{OH}} = -2.0 \ m A$ $\overline{I_{OH}} = -4.0 \ m A$	- - - -
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 2.70\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.60\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.50\\ 2.30 \leq V_{CC} < 2.70\\ 2.70 \leq V_{CC} \leq 2.70\\ 1.55 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ 1.55 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ 1.55 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ 1.55 \leq V_{CC} < 2.7$	$\begin{array}{c} \hline \textbf{Mi.} \\ \hline 0.5 \approx V_{C} \\ 2.65 \times V_{C} \\ 0.55 \times V_{C} \\ 0.50 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 1.25 \\ 2.0 \end{array}$	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 0.75 × Vc2 0.75 × Vc2 0.75 × Vc2	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	I _{OH} = -100 μA I _{OH} = -2.0 mA	-
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}30\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ \end{array}$	$\begin{array}{c} \hline \textbf{Mi.} \\ \hline 0.5 \approx V_{C} \\ 2.65 \times V_{C} \\ 0.55 \times V_{C} \\ 0.50 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 1.25 \\ 2.0 \end{array}$	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	Win 0.65 × Vc2 0.75 × Vc2 0.75 × Vc2 0.75 × Vc2 0.75 × Vc2 1.25	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	$I_{OH} = -100 \ \mu A$ $I_{OH} = -2.0 \ m A$ $I_{OH} = -4.0 \ m A$ $I_{OH} = -6.0 \ m A$	- - - -
Symbo VIH	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.11 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 2.70\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.60\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.3$	$\begin{array}{c} \hline \textbf{Mi.} \\ \hline 0.5 \simeq V_{C} \\ 2.65 \times V_{C} \\ 0.55 \times V_{C} \\ 0.55 \times V_{C} \\ 0.57 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 1.25 \\ 2.0 \\ 1.8 \\ 2.2 \end{array}$	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	$\begin{tabular}{ c c c c c } \hline Win \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 1.6 \\ \hline 2.0 \\ \hline \hline \hline \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 1.25 \\ \hline 2.0 \\ \hline \hline \hline \hline 0.75 & V_{CC} \\ \hline 1.25 \\ \hline 2.0 \\ \hline \end{tabular}$	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	$I_{OH} = -100 \ \mu A$ $\overline{I_{OH}} = -2.0 \ m A$ $\overline{I_{OH}} = -4.0 \ m A$	-
Symbo V _{IH}	I Parameter HIGH Level Input Voltage OW Level Jut Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.60\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 0\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.70\\ 0\\ 1.65 \leq V_{CC} < 2.70\\ 0\\ 1.65 \leq V_{CC} \leq 1.95\\ 0\\ 1.65 \leq V_{CC} \leq 2.70\\ 0\\ 1.65 \leq V_{CC} < 2.70\\ 0\\ 1.65 \leq V_{CC} < 2.70\\ 0\\ 1.65 \leq V_{CC} < 2.70\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0\\ 0$	$\begin{array}{c} \hline \textbf{Mi.} \\ \hline 0.5 \simeq V_{C} \\ 2.65 \times V_{C} \\ 0.55 \times V_{C} \\ 0.55 \times V_{C} \\ 0.57 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 1.25 \\ 2.0 \\ 1.8 \\ 2.2 \end{array}$	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	$\begin{tabular}{ c c c c c } \hline Win \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 1.6 \\ \hline 2.0 \\ \hline \hline \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 1.25 \\ \hline 2.0 \\ \hline 1.8 \\ \hline \end{tabular}$	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	$I_{OH} = -100 \ \mu A$ $I_{OH} = -2.0 \ m A$ $I_{OH} = -4.0 \ m A$ $I_{OH} = -6.0 \ m A$ $I_{OH} = -12.0 \ m A$	- - - - - -
Symbo V _{IH}	I Parameter HIGH Level Input Voltage OW Level Jut Voltage HIGH Level Output Voltage	$\begin{array}{c}90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} < 2.10\\ 2.70 \leq V_{CC} \leq 3.10\\ 0.90\\ 1.11 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 1.95\\ 2.50 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 2.70\\ 0.90\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.60\\ 1.65 \leq V_{CC} \leq 1.95\\ 2.30 \leq V_{CC} \leq 2.70\\ 2.70 \leq V_{CC} \leq 3.60\\ 1.10 \leq V_{CC} \leq 1.30\\ 1.40 \leq V_{CC} \leq 1.3$	$\begin{array}{c} \hline \textbf{Mi.} \\ \hline 0.5 \simeq \sqrt{C} \\ 2.65 \times V_{C} \\ 0.55 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 0.75 \times V_{C} \\ 1.25 \\ 2.0 \\ 1.8 \\ 2.2 \\ 1.7 \\ 2.4 \end{array}$	Мах С 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7 0.8	$\begin{tabular}{ c c c c c } \hline Win \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 1.6 \\ \hline 2.0 \\ \hline \hline \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.65 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 0.75 & V_{CC} \\ \hline 1.25 \\ \hline 2.0 \\ \hline 1.8 \\ \hline 2.2 \\ \hline \end{tabular}$	Mäx 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.35 x V _{CC} 0.7	v	$I_{OH} = -100 \ \mu A$ $I_{OH} = -2.0 \ m A$ $I_{OH} = -4.0 \ m A$ $I_{OH} = -6.0 \ m A$	-

	Parameter		V _{cc}		T _A = +25°C		T _A = −40°	°C to +85°	с	1	
Symbol			(V)	Mi	Min		Min	Max	Units	Cond	Conditions
V _{OL}	LOW Level		0.90			0.1		0.1			
OL	Output Voltage	1	$.10 \le V_{CC} \le 1$.30		0.1		0.1			
			.40 ≤ V _{CC} ≤ 1.			0.2		0.2			
		1	$1.65 \le V_{CC} \le 1.00$.95		0.2		0.2		$I_{OL} = 100$	JμA
			$2.30 \le V_{CC} < 2$			0.2		0.2			
		2	$2.70 \le V_{CC} \le 3.$.60		0.2		0.2			
		1	$1.10 \le V_{CC} \le 1.10$.30	0.2	25 x V _{CC}		0.25 x \	/cc	'0L -	mA
			$.40 \le V_{CC} \le 1$.60	0.25 x V _{CC}		0.25 x V _C		/cc	I _{OL} = 4.	A
		1	$.65 \le V_{CC} \le 1$.95		0.3		0.3			A
		2	$2.30 \le V_{CC} < 2$.70		0.4					.0 mA
			$2.70 \le V_{CC} \le 3$			0.4		L	4	<u> </u>	
			$2.30 \le V_{CC} < 2$			0.6		0.6		I _{O1} = 18	0A
			$2.70 \le V_{CC} \le 3.$			0.4		1.4			4
<u> </u>			$2.70 \le V_{CC} \le 3$			0.55		5		$1_{OL} = 24.$	
I _{IN}	Input Leakage Currer		0.90 to 3.60			··0.1		.J.5 ±0.5		$0 \le V_{I} \le 3$	
I _{OZ}	3-STATE Output Leal	каде	0.90 to 3.60					±0.7	A i	$V_{I} = V_{IH}$	
1	Power Off Leakage C	Current	0		<u> </u>	0.5				$\frac{1}{10} = \frac{1}{10} \leq \frac{1}{10}$	/ ₀) ≤ 3.ℓ
I _{OFF}	Quiescent Supply Cu		0.90 to 3.60			9		0.9	μ^	$\frac{1}{ V_1 = V_{1} }$	المحمد المناه
'CC	Quicacent Supply Su		0.90 to 0.00		<u> </u>		-6-	±0.9	"PA	$V_{1-1} \leq V_{1}$	
				<u> </u>				<u> </u>	<u> </u>	1.62.1	
AC	Electrical Ch	haracte	n			1	×. \	~	2	1.	
Symbol	Parameter	VCL	- 4	T _A = +25°			C tu +25°C	Units	Condit	tions	Figure Number
	Dranagatia	(V) 0.90		<u>ריי</u> ד 1.2.נ	.'lax	Mir .	Max	<u> </u>	0 15 - 5	D 1 MO	
t _{PHL}	Propagatic	1.1	30 7.0		1.8	1.9	14.9		$C_{L} = 15 \text{ pF, I}$ $C_{I} = 15 \text{ pF, I}$		
t _{PLH}		40 ≤ V _{CC} ≤		3.5	5.0	0 8	5.7		o_ = 10 pi , i	NL - 2 N32	
		.65 ≤ V _{CC} .		3.0	4.6	0.3	4.9	ns	C _L = 30 pF		Figures 1, 2
		2.30 < 1 _{CC} <		10	3.5	0.7	3.5		$R_{I} = 500\Omega$		
		2.70 ∠ V _{CC} ≤		1.0	3.1	0.5	3.3		-		
	Outr	0.90		1+.0	4				$C_L = 30 \text{ pF}$		
t _{P≿}	Linable Time	$1.10 \le V_C$		6.7	9.7	2.0	16.4	1	$R_U = 1k\Omega$		
	1,15	1.40 - V _{CC} -	1.60 1.2	4.0	6.0	1.0	7.5	ns	$R_D = 1k\Omega$		Figures
		1 65 ≤ v _{CC} ≤		3.0	4.7	0.9	5.2	115	$S_1 = GND$ fo	or t _{PZH}	1, 2
		$2.30 \le V_{CC} <$		2.0	3.5	0.7	3.7		$S_1 = V_I \text{ for } t_F$	PZL	
		2.70 ≟ V _{CC} ≤	3.00 0.5	1.2	3.1	0.4	3.4		$V_I = 2 \times V_{CC}$		
<u>_1</u>	Output	0.90		14.0	-			1	C _L = 30 pF		
t _{PHZ}			4 00 00	5.0	9.5	2.0	14.0	1	$R_U = 1k\Omega$		1
t _{PHZ} ФLZ		1.10 ≤ V _{CC} ≤									
		$1.40 \le V_{CC} \le$	1.60 1.2	3.0	5.9	1.1	7.1	ns	$R_D = 1k\Omega$		Figures
		$1.40 \le V_{CC} \le$ $1.65 \le V_{CC} \le$	1.601.21.951.0	3.0 2.0	6.3	0.8	6.5	ns	$S_1 = GND$ fo		Figures 1, 2
		$1.40 \le V_{CC} \le$ $1.65 \le V_{CC} \le$ $2.30 \le V_{CC} \le$	1.60 1.2 1.95 1.0 2.70 0.8	3.0 2.0 1.5	6.3 5.3	0.8 0.5	6.5 5.5	ns	$S_1 = GND \text{ for } S_1 = V_1 \text{ for } t_F$	PLZ	Figures 1, 2
ΨLZ	Disable Time	$1.40 \le V_{CC} \le$ $1.65 \le V_{CC} \le$ $2.30 \le V_{CC} \le$ $2.70 \le V_{CC} \le$	1.60 1.2 1.95 1.0 2.70 0.8	3.0 2.0 1.5 1.0	6.3	0.8	6.5		$S_1 = GND$ fo	PLZ	Figures 1, 2
		$1.40 \le V_{CC} \le$ $1.65 \le V_{CC} \le$ $2.30 \le V_{CC} \le$	1.60 1.2 1.95 1.0 2.70 0.8	3.0 2.0 1.5	6.3 5.3	0.8 0.5	6.5 5.5	pF	$S_1 = GND \text{ for } S_1 = V_1 \text{ for } t_F$	PLZ	Figures 1, 2

pF

 $V_I = 0V \text{ or } V_{CC}$

f = 10 MHz

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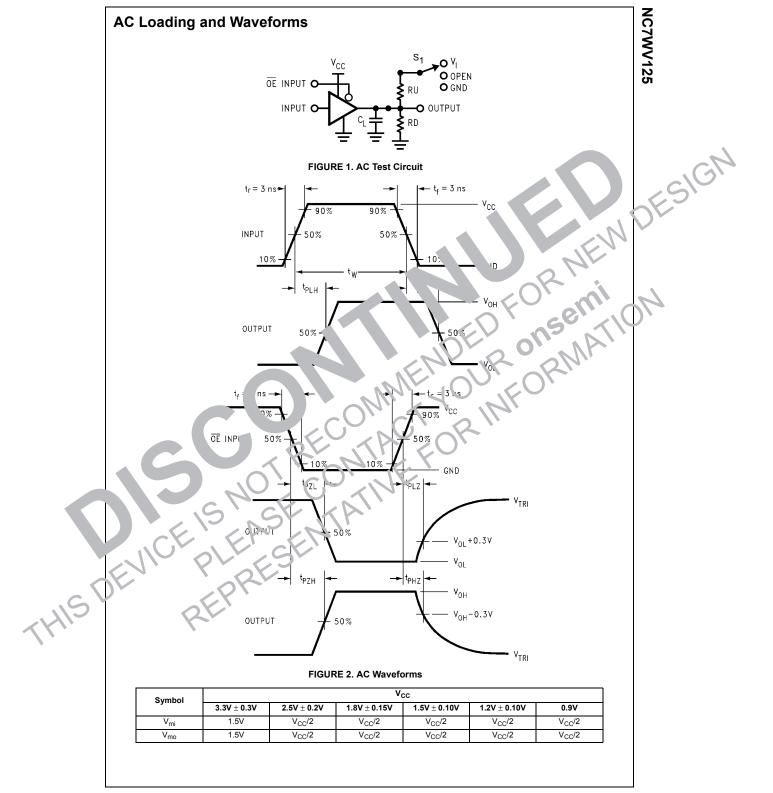
 C_{PD}

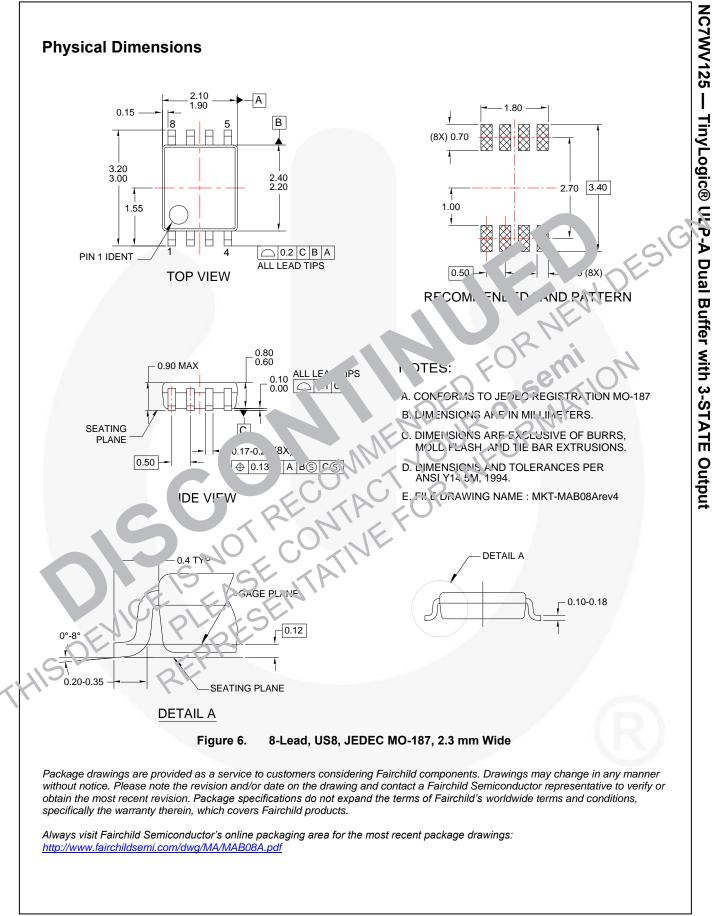
Power Dissipation

Capacitance

0.90 to 3.60

12.0







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